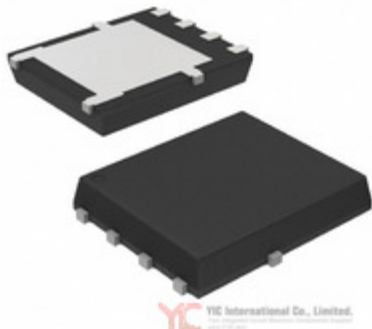
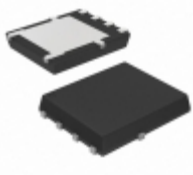
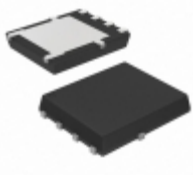
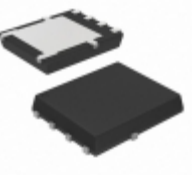
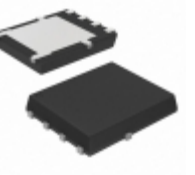
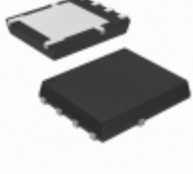
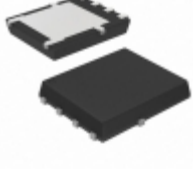
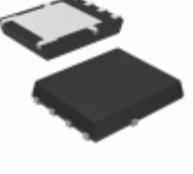
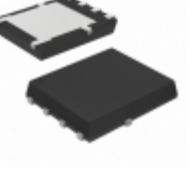
	<h2 style="color: red;">NVMF55C430NAFT1G</h2>
	Hersteller-Teilenummer: NVMF55C430NAFT1G
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 40V 35A 185A 5DFN
	Datenblätter:  NVMF55C430NAFT1G.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMF55C430NAFT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 40V 35A 185A 5DFN
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	3.5V @ 250µA
Vgs (Max)	±20V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Serie	Automotive, AEC-Q101
Rds On (Max) @ Id, Vgs	1.7 mOhm @ 50A, 10V
Verlustleistung (max)	3.8W (Ta), 106W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	8-PowerTDFN, 5 Leads
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Hersteller Standard Vorlaufzeit	42 Weeks
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Eingabekapazität (Ciss) (Max) @ Vds	3300pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	47nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Antriebsspannung (Max Rds On, Min Rds On)	10V
Drain-Source-Spannung (Vdss)	40V
detaillierte Beschreibung	N-Channel 40V 35A (Ta), 185A (Tc) 3.8W (Ta), 106W
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	35A (Ta), 185A (Tc)

NVMF55C430NAFT1G Electronic Components ist ein 100% neues Original von YIC Distributor, NVMF55C430NAFT1G-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, NVMF55C430NAFT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.
RFQ NVMF55C430NAFT1G E-Mail: Info@Y-IC.com

Sie können auch interessiert

<p>sein:</p>  <p>NVMF55C430NLT3G ON Semiconductor MOSFET N-CH 40V 200A SO8FL</p>	 <p>NVMF55C430NAFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 35A 185A 5DFN</p>	 <p>NVMF55C426NWFAFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 41A 235A 5DFN</p>	 <p>NVMF55C426NT3G ON Semiconductor MOSFET N-CH 40V SO8FL</p>
 <p>NVMF55C426NWFAFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 41A 235A 5DFN</p>	 <p>NVMF55C430NLAF1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 38A 200A 5DFN</p>	 <p>NVMF55C426NWFT1G ON Semiconductor MOSFET N-CH 40V SO8FL</p>	 <p>NVMF55C430NLAF1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 38A 200A 5DFN</p>

Verwandtes Hot-Keyword

Mehr

NVMF55C430NAFT1G AMI Semiconductor / ON Semiconductor	NVMF55C430NAFT1G Datenblatt	NVMF55C430NAFT1G-Datenblätter	NVMF55C430NAFT1G PDF	AMI Semiconductor / ON Semiconductor NVMF55C430NAFT1G
NVMF55C430NAFT1G Electronic	NVMF55C430NAFT1G-Komponenten	NVMF55C430NAFT1G-Verteiler	NVMF55C430NAFT1G-Bild	NVMF55C430NAFT1G-Teil
NVMF55C430NAFT1G Preis	NVMF55C430NAFT1G Hersteller	NVMF55C430NAFT1G Bild	NVMF55C430NAFT1G Aktie	NVMF55C430NAFT1G Inventar
NVMF55C430NAFT1G Neu	NVMF55C430NAFT1G Original	NVMF55C430NAFT1G garantiert	NVMF55C430NAFT1G RFQ	NVMF55C430NAFT1G Online bestellen

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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